



Single-Chip Electronic Volume Control System



Overview

The LC75395E is an electronic volume control that provides volume, balance, five-band equalization and input switching functions. These functions are controlled from serial input data.

Functions

- Volume control: The volume control provides 25 attenuation positions: from 0 dB to −17.5 dB in 1.25 dB steps, from −17.5 dB to −25 dB in 2.5 dB steps, from −25 dB to −36.25 dB in 3.75 dB steps and with settings for −41.25 dB, −50 dB, −60 dB and −∞.
 - A balance function can be implemented by controlling the left and right channels independently.
- Equalizer: The equalizer function supports ±10 dB control in 2 dB steps in each of the five bands. Of the five bands, four provide peaking characteristics, and one provides shelving characteristics.
- Selector: The selector function selects one of four inputs for each of the left and right channels. An arbitrary amplification level can be set for each input signal using external components.
- Serial data input: All controls can be set from serial input data (CCB format)

Features

- On-chip buffer amplifiers to minimize the number of external components
- Silicon-gate CMOS process for minimal switching noise
- On-chip circuit to generate the V_{DD}/2 reference voltage
 - CCB is a trademark of SANYO ELECTRIC CO., LTD.
 - CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

Specifications

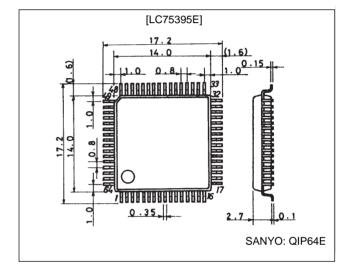
Absolute Maximum Ratings at $Ta = 25^{\circ}C$, $V_{SS} = 0$ V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max	V_{DD}	12	V
Maximum input voltage	V _{IN} max	CL, DI, CE, L1 to L4, R1 to R4, LTIN, RTIN, LVRIN, RVRIN	V_{SS} – 0.3 to V_{DD} + 0.3	V
Allowable power dissipation	Pd max	Ta ≤ 85°C	310	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +125	°C

Package Dimensions

unit: mm

3159-QFP64E



LC75395E

Allowable Operating Ranges at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply voltage	V _{DD}	V _{DD}	6.0		11.0	V
Input high level voltage	V _{IH}	CL, DI, CE	4.0		V _{DD}	V
Input low level voltage	V _{IL}	CL, DI, CE	V _{SS}		1.0	V
Input voltage amplitude	V _{IN}	CL, DI, CE, L1 to L4, R1 to R4, LTIN, RTIN, LVRIN, RVRIN	V _{SS}		V _{DD}	Vp-p
Input pulse width	t _{øW}	CL	1.0			μs
Setup time	t _{SETUP}	CL, DI, CE	1.0			μs
Hold time	t _{HOLD}	CL, DI, CE	1.0			μs
Operating frequency	fopg	CL			500	kHz

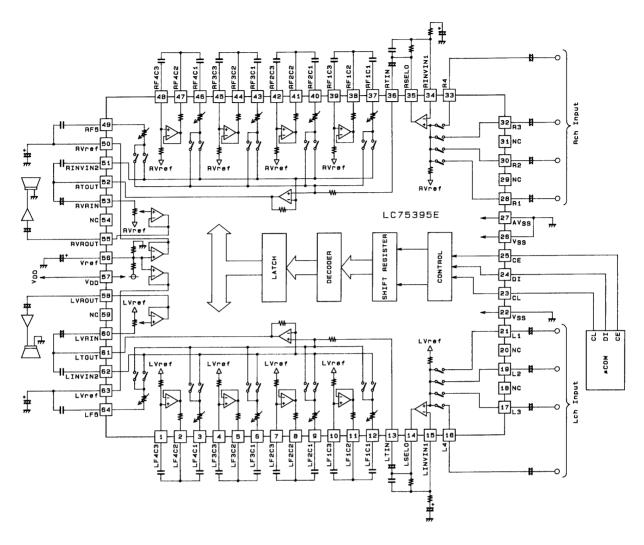
Electrical Characteristics at $Ta=25^{\circ}C,\,V_{DD}=10~V,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	min	typ	max	Unit
[Input Block]						
Input resistance	Rin	L1 to L4, R1 to R4		1		MΩ
Clipping level	Vcl	LSELO, RSELO: THD = 1.0%		2.65		Vrms
Output load resistance	R _L	LSELO, RSELO	3			kΩ
[Volume Control Block]						
Input resistance	Rin	LVRIN, RVRIN	21	35	49	kΩ
[Equalizer Control Block]						
Control range	Geq	Max, boost/cut	±8	±10	±12	dB
Step resolution	Estep		1	2	3	dB
Internal feedback resistance	Rfeed		17	28	39	kΩ
[Overall Characteristics]						
Total harmonic distortion	THD (1)	V _{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall		0.0033		%
	THD (2)	V _{IN} = 1 Vrms, f = 20 kHz, with all controls flat overall		0.012		%
Crosstalk	СТ	V_{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall Rg = 1 k Ω		86		dB
Output at maximum attenuation	V _O min	V_{IN} = 1 Vrms, f = 1 kHz, with the main volume control at $-\infty$		-84		dB
	V _N (1)	With all controls flat overall (IHF-A), Rg = 1 k Ω		3.9		μV
Output noise voltage	V _N (2)	With all controls flat overall (DIN-AUDIO), $Rg = 1 \; k\Omega$		5.4		μV
Current drain	I _{DD}	$V_{DD} - V_{SS} = 11 \text{ V}$		25	33	mA
Input high level current	I _{IH}	CL, DI, CE: V _{IN} = 11 V			10	μA
Input low level current	I _{IL}	CL, DI, CE: V _{IN} = 0 V	-10			μA

Input Amplifier Characteristics at $Ta=25^{\circ}C,\,V_{DD}-V_{SS}=10~V$

Parameter	Symbol	Conditions	min	typ	max	Unit
Input offset voltage	V _{IO}		-10		+10	mV
Input offset current	I _{IO}	$V_{SS} \le V_{IN} \le V_{DD}$		±10		nA
Open-loop voltage gain	A _O			80		dB
0 dB bandwidth	f _T			2.5		MHz
Allowable load resistance	R _L		3			kΩ

Equivalent Circuit Block Diagram and Sample Application Circuit

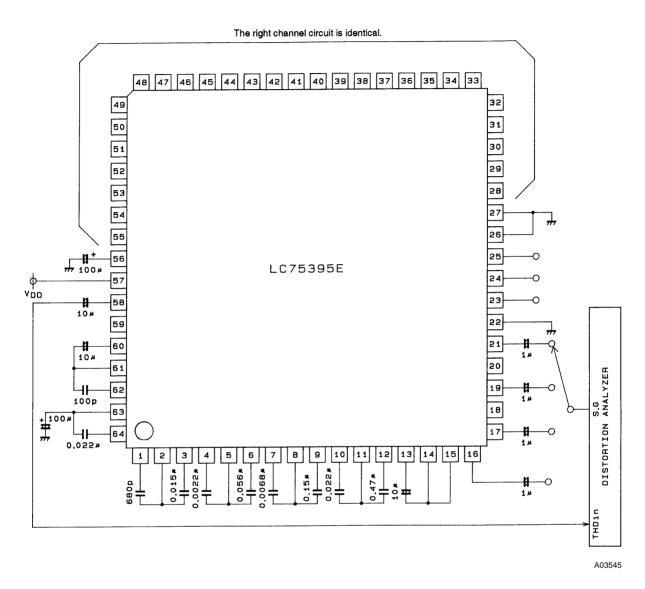


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Note: If at all possible, use bipolar capacitors for all capacitors that do not have a polarity specified.

Test Circuits

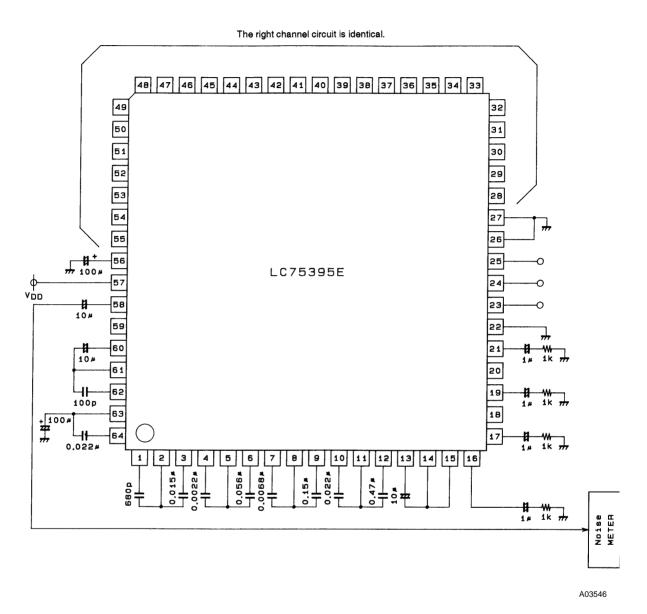
1. Total Harmonic Distortion



Unit (capacitance: F)

Test Circuits

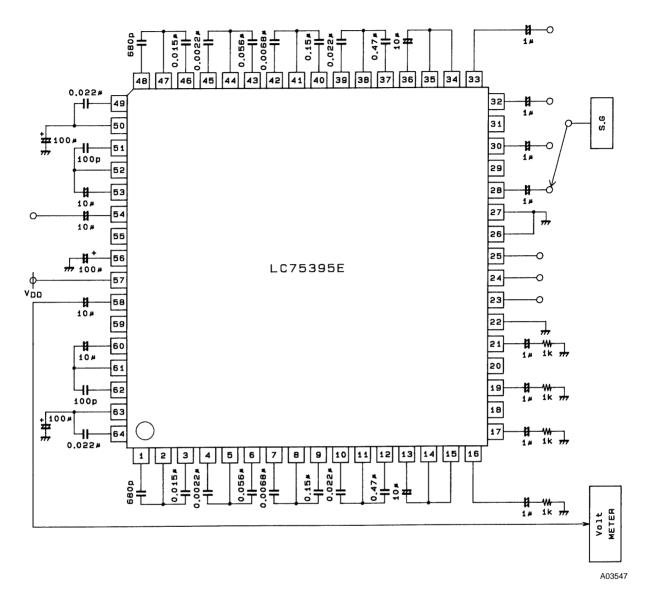
2. Output Noise Voltage



Unit (resistance: Ω , capacitance: F)

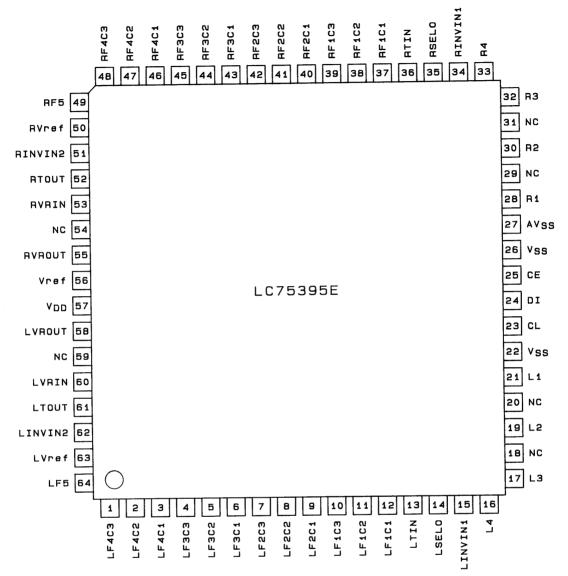
Test Circuits

3. Crosstalk



Unit (resistance: Ω , capacitance: F)

Pin Assignment



A03548

Top view

LC75395E

Pin Functions

Pin No.	Symbol	Function	Note
12	LF1C1		7.53
11	LF1C2	The left channel F1 band control block.	
10	LF1C3	These are external capacitor connections.	
37	RF1C1		- •∨□□
38	RF1C2	The right channel F1 band control block.	₩ FnC1
39	RF1C3	These are external capacitor connections.	
9	LF2C1		
8	LF2C2	The left channel F2 band control block.	₹ • V DD
7	LF2C3	These are external capacitor connections.	Vref
40	RF2C1		- - -
41	RF2C2	The right channel F2 band control block.	v _{DD}
42	RF2C3	These are external capacitor connections.	Fnc2
6	LF3C1		*
5	LF3C2	The left channel F3 band control block.	≱ •∨□□
4	LF3C3	These are external capacitor connections.	AVSS FnC3
43	RF3C1		_ _
44	RF3C2	The right channel F3 band control block.	## 8VDD
45	RF3C3	These are external capacitor connections.	° VDD
3	LF4C1		Vref
2	LF4C2	The left channel F4 band control block.	* -
1	LF4C3	These are external capacitor connections.	A03549
46	RF4C1		
47	RF4C2	The right channel F4 band control block. These are external capacitor connections.	
48	RF4C3	These are external capacitor connections.	
13 36	LTIN RTIN	Tone control inputs These must be driven by low-impedance circuits.	A03550
14 35	LSELO RSELO	Input selector outputs	Vref AVSS AVSS A03551
			9400
64	LF5	F5 band control block.	
49	RF5	These are external capacitor connections.	A03552
21	L1		
19	L2		ومرا
17	L3		
16	L4	Signal inputs	
28	R1		
30 32	R2 R3		AVSS O OVER A03553
32	R3 R4		
		Power supply	
57	V _{DD}	Power supply	-
22, 26	V _{SS}	Internal logic system ground	-
27	AV _{SS}	Internal operational amplifier ground	

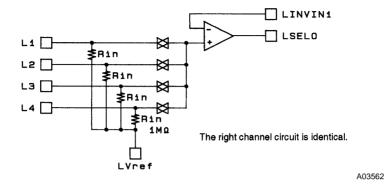
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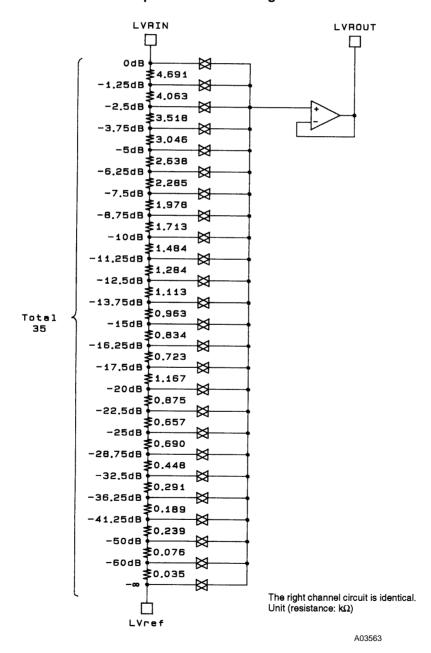
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Pin No.	Symbol	Function	Note
56	Vref	$\rm V_{DD}/2$ voltage generation block. A capacitor must be inserted between Vref and $\rm V_{SS}$ to suppress power supply ripple.	LVrefo RVref AVSS , A04449
63 50	LVref RVref	Common pins for the volume control, tone control and input switching blocks. Since capacitors inserted between LVref (or RVref) and V _{SS} become the residual resistance when the volume control is set at maximum attenuation, the values of these capacitors must be chosen carefully. A voltage higher than V _{DD} must never be applied.	→ VDD ★ → □ A03555
15 34	LINVIN1 RINVIN1	Inverting inputs for the operational amplifiers that set the input gain.	AVSS A03556
62 51	LINVIN2 RINVIN2	Inverting inputs for the graphic equalizer operational amplifiers. Unnecessary frequency bands can be excluded and oscillation prevented by inserting arbitrary capacitors between the INVIN2 and TOUT pins.	AVSS A03557
61 52	LTOUT RTOUT	Tone control outputs	A03558
60 53	LVRIN RVRIN	Volume control inputs These must be driven by low-impedance circuits.	→ VpD → → → → → → → → → → → → → → → → → → →
58 55	LVROUT RVROUT	Volume control outputs	A03560
25	CE	Chip enable Data is read into the internal latches and the analog switches operate when this pin goes from high to low. Data transfer is enabled when this pin is high.	Z A03561
24 23	DI CL	Serial data and clock connections for chip control	- /// A03561
18 20 29 31 54 59	NC NC NC NC NC	Unused pins	

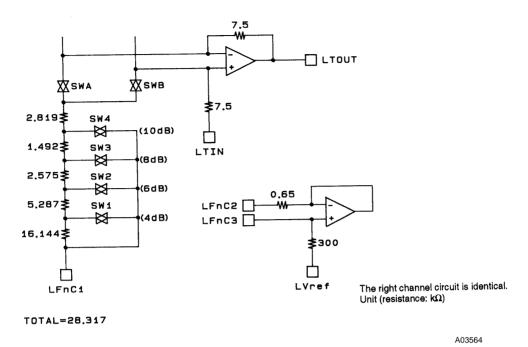
Input Block Internal Equivalent Circuit Diagram



Volume Control Block Internal Equivalent Circuit Diagram



Equalizer Control Block Internal Equivalent Circuit (bands F1 to F4)

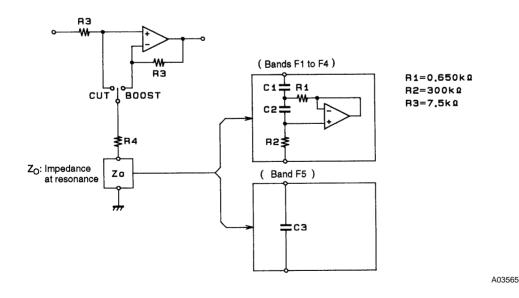


External Capacitor Calculations

The LC75395E supports four bands with peaking characteristics and one band with shelving characteristics.

- 1. Peaking Characteristics (bands F1 to F4)

 The external capacitor functions as the structural element of a simulated inductor. The equivalent circuit and the calculations required to achieve the desired center frequency are shown below.
 - Equivalent circuit for the simulated inductor



• Sample Calculation

Specifications 1) Center frequency
$$F_O = 107~Hz$$

2) Q at maximum boost: $Q_{+10~dB} = 0.8$

 $\ensuremath{\textcircled{1}}$ Derive the sharpness (QO) of the simulated inductor itself.

$$Q_{O} = (R1 + R4)/R1 \times Q_{+10 \text{ dB}}$$

 $\neq 4.270$

2 Derive C1.

$${\rm C1} = 1/2\pi {\rm F_O} {\rm R1Q_O} \neq 0.536~(\mu {\rm F})$$

3 Derive C2.

$$C2 = Q_{O}/2\pi F_{O}R2 \neq 0.021~(\mu F)$$

• Sample values for C1 and C2

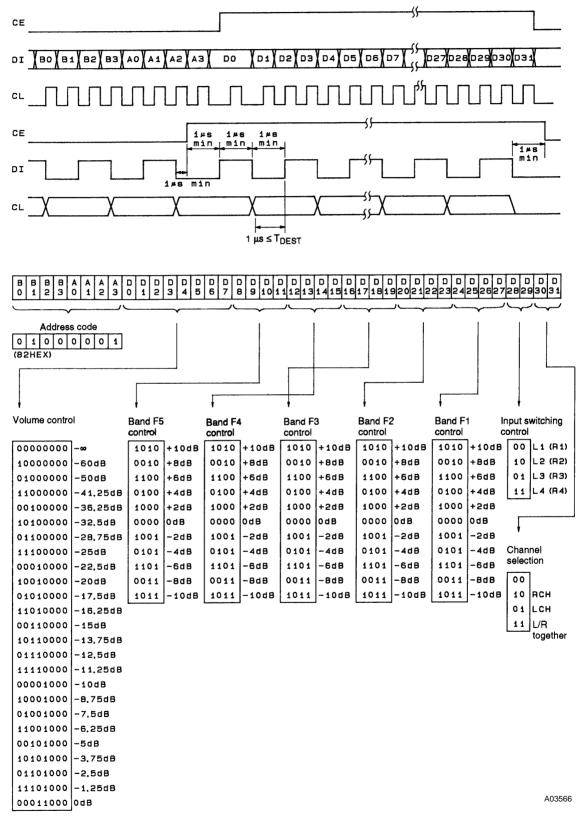
Center frequency F _O (Hz)	C1 (F)	C2 (F)
107	0.536 μ	0.021 μ
340	0.169 μ	6663 p
1070	0.054 μ	2117 p
3400	0.017 μ	666 p

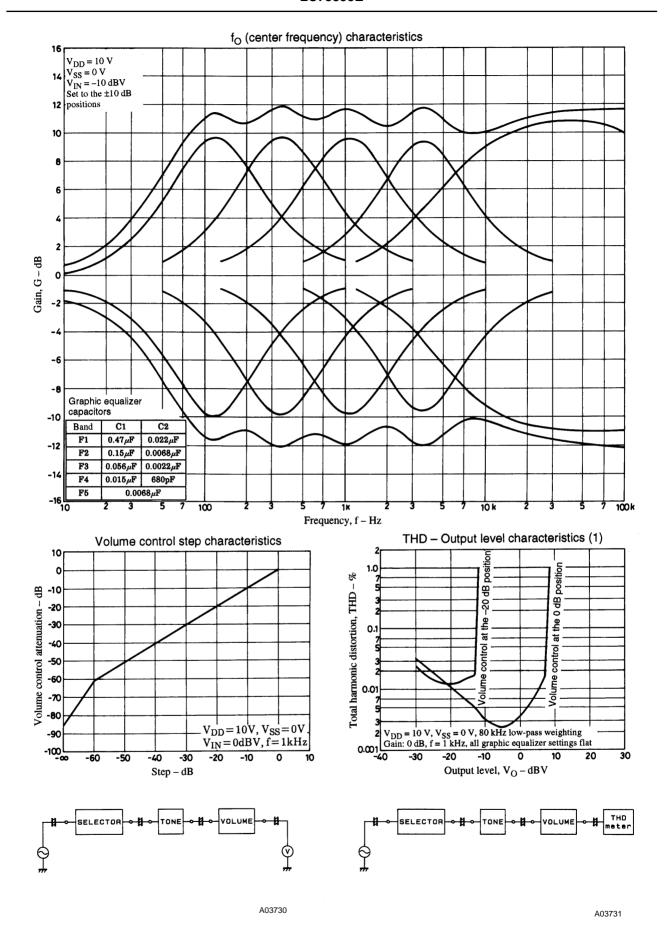
2. Shelving Characteristics (band F5)

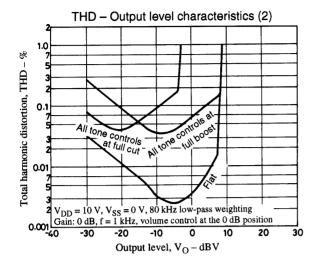
To achieve ± 10 dB (in 2 dB steps) at the target frequency, use an external capacitor C3 which has an impedance of 650 Ω .

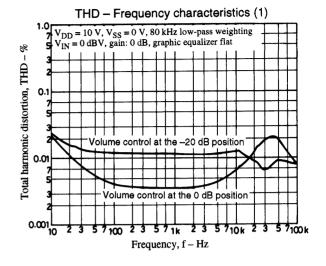
Control System Timing and Data Format

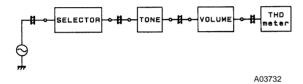
The LC75395E is controlled by inputting stipulated data to the CE, CL, and DI pins. The data consists of a total of 40 bits, of which 8 bits are address and 32 bits are data.

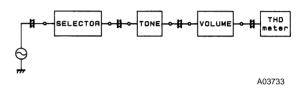


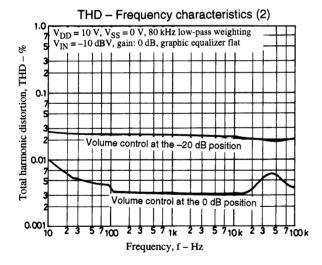


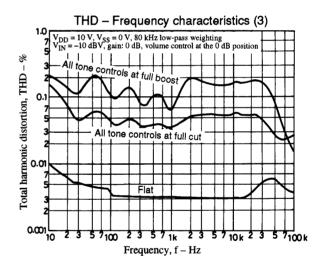


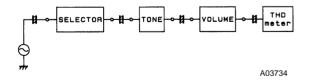


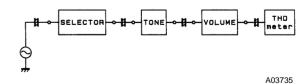


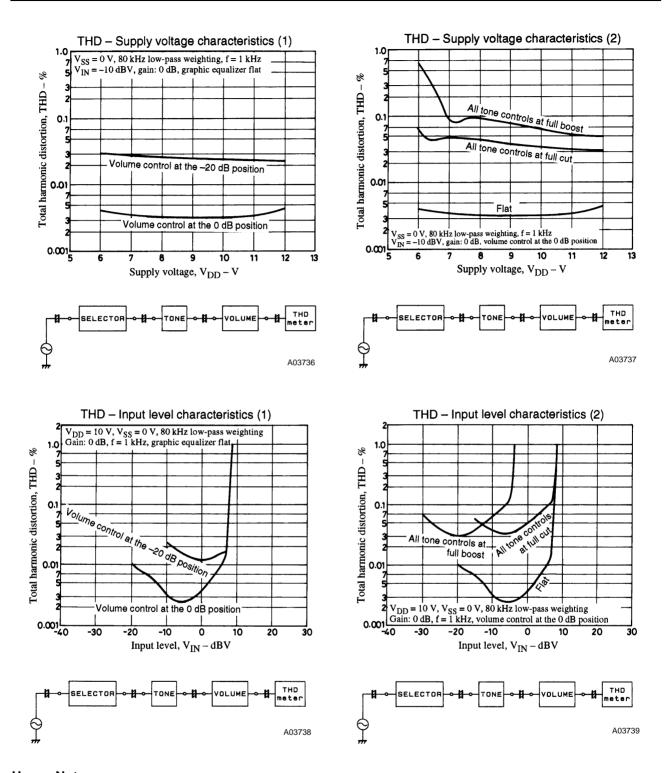












Usage Notes

- 1. The states of the internal analog switches are undefined when power is first applied. Muting should be applied externally until control data has been transferred and stored.
- 2. The signal lines for the CL, DI and CE pins should either be covered by the pattern ground or be formed from shielded cable to prevent the high-frequency digital signals transmitted over these lines from entering the analog system.

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